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Alexandria, VA 22313-1430, on March 9, 200

Sue Bromaghim

March 9, 2006

**CUSTOMER NO. 36257** 

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Jeffrey W. LUTZE et al.

Title:

Self Aligned Non-Volatile Memory Cells and Processes for Fabrication

Application No.:

10/799,060

Filing Date:

March 12, 2004

Examiner:

Mai Huong C. TRAN

Group Art Unit:

2818

Docket No.:

SNDK.352US0

Conf. No.:

6740

Mail Stop RCE Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

## SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

Sir:

Pursuant to 37 C.F.R. §§ 1.56, 1.97 and 1.98, Applicant(s) call(s) the documents listed on the enclosed Form PTO-1449 to the Examiner's attention in this patent application.

According to 37 C.F.R. 1.98(2)(ii), copies of the U.S. Patents and U.S. Published Patent Applications documents are not required and are therefore not enclosed. Copies of the listed foreign patent documents or Other Art are enclosed.

Attorney Docket No.: SNDK.352US0

**Application No.: 10/799,060** 

Citation of these documents shall not be construed as (1) an admission that the documents are prior art with respect to the invention or inventions claimed in this application, (2) a representation that a search has been made (other than as indicated by any cited document), or (3) an admission that the cited information is, or is considered to be, material to patentability as defined in § 1.56(b).

This information disclosure statement is submitted under 37 C.F.R. § 1.97(b) and consequently no fee should be required. The Commissioner is authorized, however, to charge any fee that may be required, or to credit any overpayment, against Deposit Account No. 502664.

Respectfully submitted,

Gerald P. Parsons

<u>viaicii 7, 200</u>

Date

Reg. No. 24,486

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<sup>\*</sup>EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with your communication to applicant.

U.S. Depart	tment c	of Commerce, Patent a	and Trademark	Atty. Docket No.			Application No.				
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